Operational Amplifiers, Single Supply, High Slew Rate, Low Input Offset Voltage

The MC33272/74 series of monolithic operational amplifiers are quality fabricated with innovative Bipolar design concepts. This dual and quad operational amplifier series incorporates Bipolar inputs along with a patented Zip–R–Trim element for input offset voltage reduction. The MC33272/74 series of operational amplifiers exhibits low input offset voltage and high gain bandwidth product. Dual –doublet frequency compensation is used to increase the slew rate while maintaining low input noise characteristics. Its all NPN output stage exhibits no deadband crossover distortion, large output voltage swing, and an excellent phase and gain margin. It also provides a low open loop high frequency output impedance with symmetrical source and sink AC frequency performance.

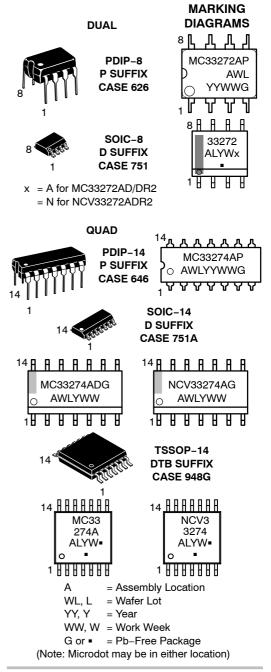
Features

- Input Offset Voltage Trimmed to 100 µV (Typ)
- Low Input Bias Current: 300 nA
- Low Input Offset Current: 3.0 nA
- High Input Resistance: 16 M Ω
- Low Noise: $18 \text{ nV} / \sqrt{\text{Hz}} @ 1.0 \text{ kHz}$
- High Gain Bandwidth Product: 24 MHz @ 100 kHz
- High Slew Rate: 10 V/µs
- Power Bandwidth: 160 kHz
- Excellent Frequency Stability
- Unity Gain Stable: w/Capacitance Loads to 500 pF
- Large Output Voltage Swing: +14.1 V/ -14.6 V
- Low Total Harmonic Distortion: 0.003%
- Power Supply Drain Current: 2.15 mA per Amplifier
- Single or Split Supply Operation: +3.0 V to +36 V or ±1.5 V to ±18 V
- ESD Diodes Provide Added Protection to the Inputs
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- Pb–Free Packages are Available



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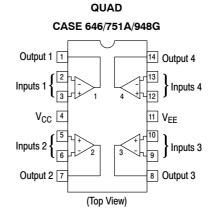


ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 11 of this data sheet.

PIN CONNECTIONS

DUAL CASE 626/751 Output 1 ₿ V_{CC} 7 Output 2 Inputs 1 [3 Inputs 2 V_{EE} (Top View)



MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Supply Voltage		V_{CC} to V_{EE}	+36	V
Input Differential Voltage Range		V _{IDR}	Note 1	V
Input Voltage Range		V _{IR}	Note 1	V
Output Short Circuit Duration (Note 2)		t _{SC}	Indefinite	sec
Maximum Junction Temperature		Τ _J	+150	°C
Storage Temperature		T _{stg}	-60 to +150	°C
ESD Protection at Any Pin	– Human Body Model – Machine Model	V _{esd}	2000 200	V
Maximum Power Dissipation		PD	Note 2	mW
Operating Temperature Range	MC33272A, MC33274A NCV33272A, NCV33274A	T _A	-40 to +85 -40 to +125	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Either or both input voltages should not exceed V_{CC} or V_{EE}.
 Power dissipation must be considered to ensure maximum junction temperature (T_J) is not exceeded (see Figure 2).

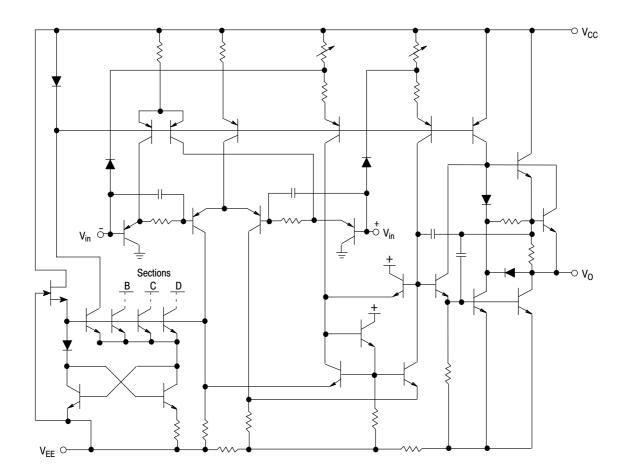
Characteristics	Figure	Symbol	Min	Тур	Max	Unit
Input Offset Voltage ($R_S = 10 \Omega$, $V_{CM} = 0 V$, $V_O = 0 V$) ($V_{CC} = +15 V$, $V_{EE} = -15 V$) $T_A = +25^{\circ}C$ $T_A = -40^{\circ} to +85^{\circ}C$ $T_A = -40^{\circ} to +125^{\circ}C$ (NCV33272A) $T_A = -40^{\circ} to +125^{\circ}C$ (NCV33274A) ($V_{CC} = 5.0 V$, $V_{EE} = 0$)	3	Vıo	- - - -	0.1 _ _ _	1.0 1.8 2.5 3.5	mV
$T_{A} = +25^{\circ}C$			-	-	2.0	
Average Temperature Coefficient of Input Offset Voltage R_S = 10 Ω , V_{CM} = 0 V, V_O = 0 V, T_A = -40° to +125°C	3	$\Delta V_{IO} / \Delta T$	_	2.0	_	μV/°C
Input Bias Current (V _{CM} = 0 V, V _O = 0 V) $T_A = +25^{\circ}C$ $T_A = T_{low}$ to T_{high}	4, 5	Ι _{ΙΒ}		300 -	650 800	nA
Input Offset Current (V _{CM} = 0 V, V _O = 0 V) $T_A = +25^{\circ}C$ $T_A = T_{low}$ to T_{high}		I _{IO}		3.0 _	65 80	nA
Common Mode Input Voltage Range (ΔV_{IO} = 5.0 mV, V_O = 0 V) T _A = +25°C	6	V _{ICR}	V _{EE}	to (V _{CC} -	1.8)	V
Large Signal Voltage Gain (V _O = 0 V to 10 V, R _L = 2.0 k Ω) T _A = +25°C T _A = T _{low} to T _{high}	7	A _{VOL}	90 86	100 -		dB
	8, 9, 12	V ₀ + V ₀ - V ₀ + V ₀ - V _{0L} V _{0H}	13.4 - 13.4 - 3.7	13.9 -13.9 14 -14.7 -	-13.5 - -14.1 0.2 5.0	V
Common Mode Rejection (V _{in} = +13.2 V to -15 V)	13	CMR	80	100	-	dB
Power Supply Rejection V_{CC}/V_{EE} = +15 V/ –15 V, +5.0 V/ –15 V, +15 V/ –5.0 V	14, 15	PSR	80	105	-	dB
Output Short Circuit Current (V _{ID} = 1.0 V, Output to Ground) Source Sink	16	I _{SC}	+25 -25	+37 -37		mA
Power Supply Current Per Amplifier ($V_O = 0 V$) ($V_{CC} = +15 V$, $V_{EE} = -15 V$) $T_A = +25^{\circ}C$ $T_A = T_{low}$ to T_{high}	17	Icc		2.15	2.75 3.0	mA
$(V_{CC} = 5.0 \text{ V}, V_{EE} = 0 \text{ V})$ $T_A = +25^{\circ}\text{C}$			-	-	2.75	

DC ELECTRICAL CHARACTERISTICS	$(V_{CC} = +15 V, V_{CC} = -15 V, T_{A} = 10 V$	25°C, unless otherwise noted.)
DO LELOTINOAL ONANAOTENIOTIOO	$(v_{1}) = +10$ v, $v_{FF} = -10$ v, $I_A = 10$	

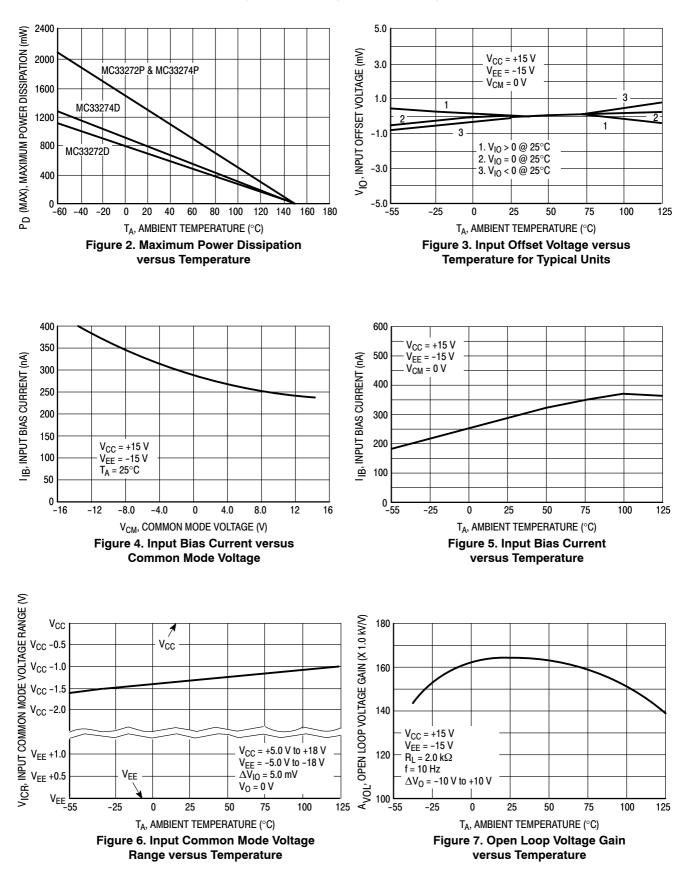
3. MC33272A, MC33274A $T_{low} = -40^{\circ}C$ $T_{high} = +85^{\circ}C$ NCV33272A, NCV33274A $T_{low} = -40^{\circ}C$ $T_{high} = +125^{\circ}C$

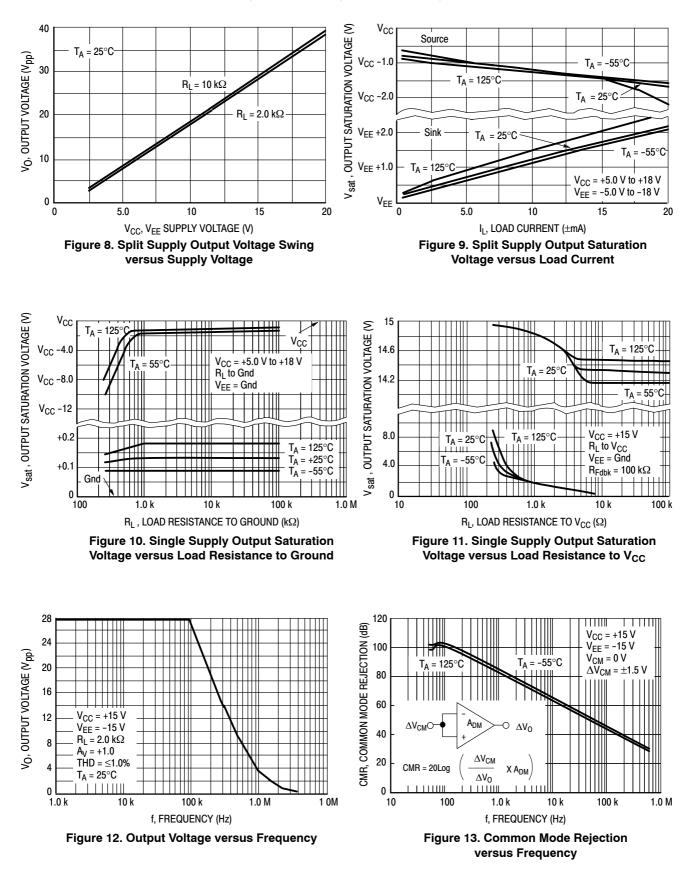
Characteristics	Figure	Symbol	Min	Тур	Max	Unit
Slew Rate (V _{in} = -10 V to +10 V, R _L = 2.0 kΩ, C _L = 100 pF, A _V = +1.0 V)	18, 33	SR	8.0	10	_	V/µs
Gain Bandwidth Product (f = 100 kHz)	19	GBW	17	24	-	MHz
AC Voltage Gain (R _L = 2.0 k Ω , V _O = 0 V, f = 20 kHz)	20, 21, 22	A _{VO}	-	65	-	dB
Unity Gain Bandwidth (Open Loop)		BW	-	5.5	-	MHz
Gain Margin (R _L = 2.0 k Ω , C _L = 0 pF)	23, 24, 26	A _m	-	12	-	dB
Phase Margin (R_L = 2.0 k Ω , C_L = 0 pF)	23, 25, 26	φ _m	-	55	-	Deg
Channel Separation (f = 20 Hz to 20 kHz)	27	CS	-	-120	-	dB
Power Bandwidth (V_O = 20 V_{pp,} R_L = 2.0 k\Omega, THD \leq 1.0%)		BW _P	-	160	-	kHz
Total Harmonic Distortion (R _L = 2.0 kΩ, f = 20 Hz to 20 kHz, V _O = 3.0 V _{rms} , A _V = +1.0)	28	THD	_	0.003	_	%
Open Loop Output Impedance ($V_0 = 0 V$, f = 6.0 MHz)	29	Z _O	-	35	-	Ω
Differential Input Resistance (V _{CM} = 0 V)		R _{in}	-	16	-	MΩ
Differential Input Capacitance (V _{CM} = 0 V)		C _{in}	-	3.0	-	pF
Equivalent Input Noise Voltage (R _S = 100 Ω , f = 1.0 kHz)	30	e _n	-	18	-	nV/√H:
Equivalent Input Noise Current (f = 1.0 kHz)	31	i _n	-	0.5	-	pA/√Hz

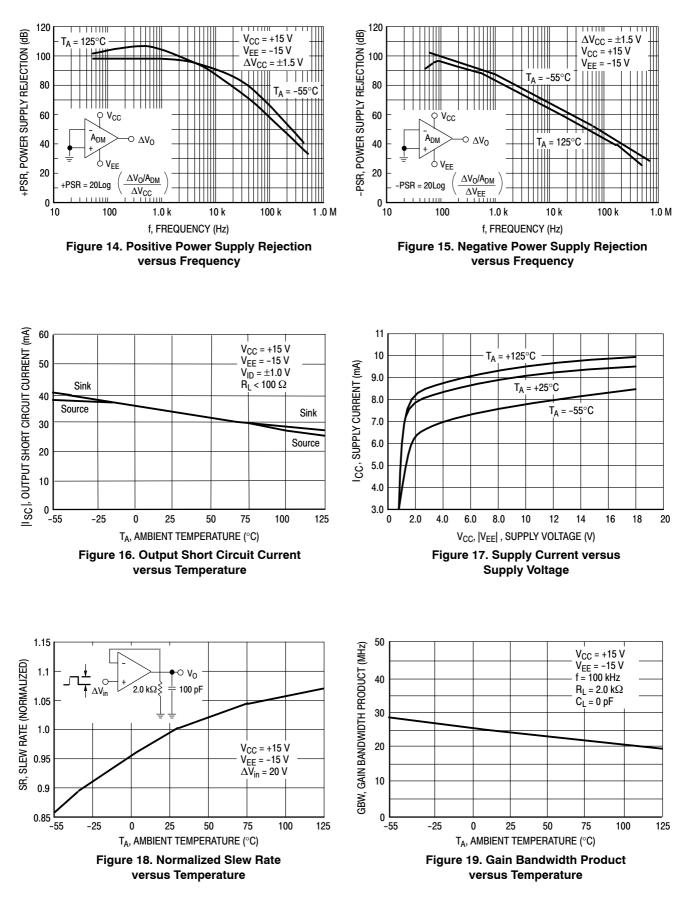
AC ELECTRICAL CHARACTERISTICS (V_{CC} = +15 V, V_{EE} = -15 V, T_A = 25°C, unless otherwise noted.)

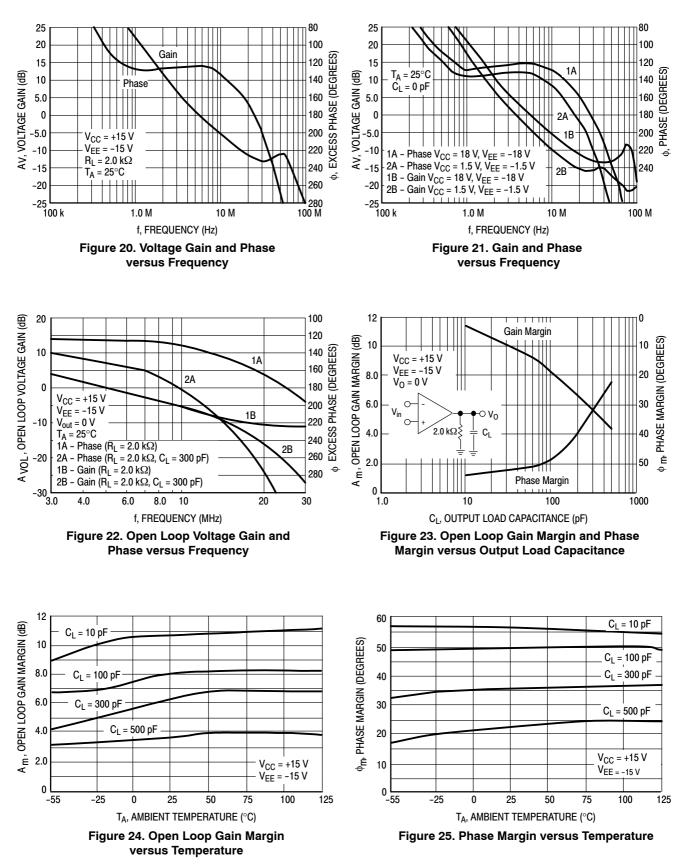


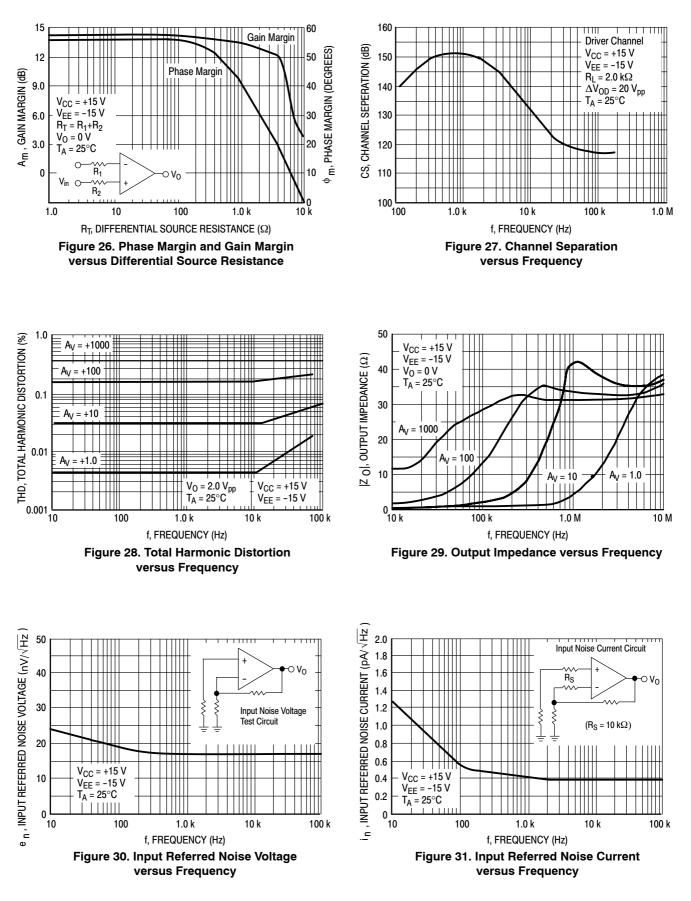


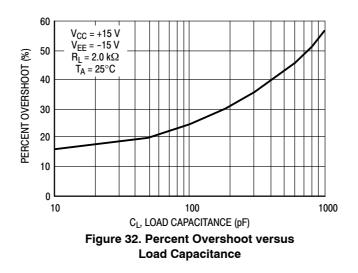


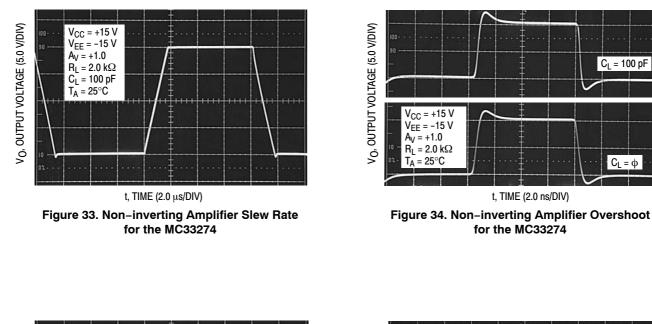


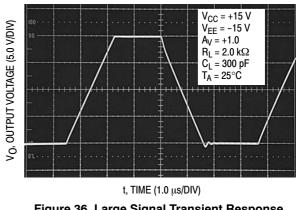






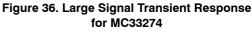






 $C_{L} = 100 \, pF$

 $C_L = \phi$





V_O, OUTPUT VOLTAGE (50 mV/DIV)

V_{CC} = +15 V

 $V_{EE} = -15 V$

 $R_L = 2.0 k\Omega$

 $C_{L} = 300 \, pF$

T_A = 25°Ċ

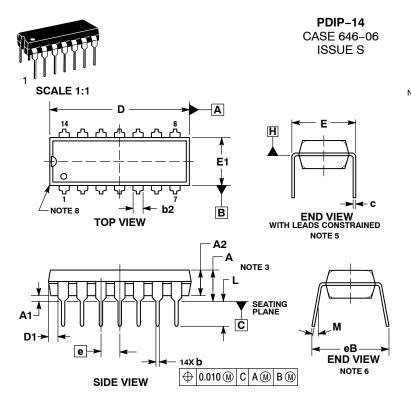
 $A_V = +1.0$

ORDERING INFORMATION

Device	Package	Shipping [†]	
MC33272AD	SOIC-8		
MC33272ADG	SOIC-8 (Pb-Free)	98 Units / Rail	
MC33272ADR2	SOIC-8		
MC33272ADR2G	SOIC-8 (Pb-Free)	2500 / Tape & Reel	
MC33272AP	PDIP-8		
MC33272APG	PDIP-8 (Pb-Free)	50 Units / Rail	
NCV33272ADR2*	SOIC-8		
NCV33272ADR2G*	SOIC-8 (Pb-Free)	2500 / Tape & Reel	
MC33274AD	SOIC-14		
MC33274ADG	SOIC-14 (Pb-Free)	55 Units / Rail	
MC33274ADR2	SOIC-14		
MC33274ADR2G	SOIC-14 (Pb-Free)		
MC33274ADTBR2G	TSSOP-14 (Pb-Free)		
MC33274AP	PDIP-14		
MC33274APG	PDIP-14 (Pb-Free)	25 Units / Rail	
NCV33274AD*	SOIC-14		
NCV33274ADG*	SOIC-14 (Pb-Free)	55 Units / Rail	
NCV33274ADR2*	SOIC-14		
NCV33274ADR2G*	SOIC-14 (Pb-Free)		
NCV33274ADTBR2G*	TSSOP-14 (Pb-Free)	1	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
 *NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP

Capable.



STYLES ON PAGE 2

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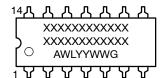


DATE 22 APR 2015

- NOTES:
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: INCHES.
 DIMENSIONS A, A1 AND L ARE MEASURED WITH THE PACK-AGE SEATED IN JEDEC SEATING PLANE GAUGE GS-3.
 DIMENSIONS D, D1 AND E1 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS ARE NOT DE VICE DA 10 INCH. NOT TO EXCEED 0.10 INCH. DIMENSION E IS MEASURED AT A POINT 0.015 BELOW DATUM
- 5. PLANE H WITH THE LEADS CONSTRAINED PERPENDICULAR TO DATUM C.
- 6.
- DIMENSION & BIS MEASURED AT THE LEAD TIPS WITH THE LEADS UNCONSTRAINED. DATUM PLANE H IS COINCIDENT WITH THE BOTTOM OF THE LEADS, WHERE THE LEADS EXIT THE BODY. PACKAGE CONTOUR IS OPTIONAL (ROUNDED OR SQUARE CODNEPS) 7.
- 8. CORNERS).

	,			
	INC	HES	MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α		0.210		5.33
A1	0.015		0.38	
A2	0.115	0.195	2.92	4.95
b	0.014	0.022	0.35	0.56
b2	0.060) TYP	1.52	TYP
С	0.008	0.014	0.20	0.36
D	0.735	0.775	18.67	19.69
D1	0.005		0.13	
Е	0.300	0.325	7.62	8.26
E1	0.240	0.280	6.10	7.11
е	0.100	BSC	2.54	BSC
eB		0.430		10.92
L	0.115	0.150	2.92	3.81
М		10°		10°

GENERIC **MARKING DIAGRAM***



XXXXX = Specific Device Code

- = Assembly Location
- WL = Wafer Lot
- YY = Year

А

G

- ww = Work Week
 - = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " .", may or may not be present.

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PDIP-14 CASE 646-06 ISSUE S

DATE 22 APR 2015

STYLE 1: PIN 1. COLLECTOR 2. BASE 3. EMITTER 4. NO CONNECTION 5. EMITTER 6. BASE 7. COLLECTOR 8. COLLECTOR 9. BASE 10. EMITTER 11. NO CONNECTION 12. EMITTER 13. BASE 14. COLLECTOR	STYLE 2: CANCELLED	STYLE 3: CANCELLED	STYLE 4: PIN 1. DRAIN 2. SOURCE 3. GATE 4. NO CONNECTION 5. GATE 6. SOURCE 7. DRAIN 8. DRAIN 9. SOURCE 10. GATE 11. NO CONNECTION 12. GATE 13. SOURCE 14. DRAIN
STYLE 5: PIN 1. GATE 2. DRAIN 3. SOURCE 4. NO CONNECTION 5. SOURCE 6. DRAIN 7. GATE 8. GATE 9. DRAIN 10. SOURCE 11. NO CONNECTION 12. SOURCE 13. DRAIN 14. GATE	STYLE 6: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 7: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 8: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 9: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE	STVLE 10: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 11: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 12: PIN 1. COMMON CATHODE 2. COMMON ANODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. COMMON ANODE 7. COMMON CATHODE 8. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. ANODE/CATHODE 14. ANODE/CATHODE 14. ANODE/CATHODE

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*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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SOIC-8 NB CASE 751-07 **ISSUE AK**

STYLE 1: PIN 1. EMITTER COLLECTOR 2. 3. COLLECTOR 4. EMITTER 5. EMITTER BASE 6. 7 BASE EMITTER 8. STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN DRAIN 4. GATE 5. 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6 BASE. DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3 GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. DRAIN 8. STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. TXE 4. 5. RXE 6. VFF 7. GND 8. ACC STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 3 CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C REXT З. 4. GND 5. IOUT IOUT 6. IOUT 7. 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. 2 EMITTER, #1 BASE, #2 З. EMITTER, #2 4. 5 COLLECTOR, #2 COLLECTOR, #2 6.

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 3. 4 COLLECTOR, #2 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: GROUND PIN 1. BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6 BIAS 2 INPUT 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE 3 P-SOURCE P-GATE 4. P-DRAIN 5 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18: PIN 1. ANODE ANODE 2. SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. CATHODE 8. STYLE 22 PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3 COMMON CATHODE/VCC 4. I/O LINE 3 COMMON ANODE/GND 5. 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND STYLE 26: PIN 1. GND 2 dv/dt З. ENABLE 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: DRAIN 1 PIN 1. DRAIN 1 2 GATE 2 З. SOURCE 2 4 SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5.

6.

7.

8 GATE 1

SOURCE 1/DRAIN 2

STYLE 3: PIN 1. DRAIN, DIE #1 DRAIN, #1 2. DRAIN, #2 З. DRAIN, #2 4. GATE, #2 5. SOURCE, #2 6. 7 GATE #1 8. SOURCE, #1 STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS THIRD STAGE SOURCE GROUND З. 4. 5. DRAIN 6. GATE 3 SECOND STAGE Vd 7. FIRST STAGE Vd 8. STYLE 11: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. З. GATE 2 4. 5. DRAIN 2 6. DRAIN 2 DRAIN 1 7. 8. DRAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 ANODE 1 3 ANODE 1 4. 5. CATHODE, COMMON CATHODE, COMMON CATHODE, COMMON 6. 7. CATHODE, COMMON 8. STYLE 19: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 MIRROR 1 8. STYLE 23: PIN 1. LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND 2. 3 LINE 2 IN 4. LINE 2 OUT 5. COMMON ANODE/GND COMMON ANODE/GND 6. 7. 8. LINE 1 OUT STYLE 27: PIN 1. ILIMIT OVI O 2 UVLO З. 4. INPUT+ 5. 6. SOURCE SOURCE SOURCE 7. 8 DRAIN

DATE 16 FEB 2011

STYLE 4: PIN 1. 2. ANODE ANODE ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 З. BASE #2 COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE 2. 3. GATE 4. 5. DRAIN 6 DRAIN DRAIN 7. 8. DRAIN STYLE 16 EMITTER, DIE #1 PIN 1. 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE EMITTER 2. 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE 6. CATHODE COLLECTOR/ANODE 7. 8. COLLECTOR/ANODE STYLE 28: PIN 1. SW_TO_GND 2. DASIC OFF DASIC_SW_DET З. 4. GND 5. 6. V MON VBULK 7. VBULK 8 VIN

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7.

8

COLLECTOR, #1

COLLECTOR, #1

DUSEM

0.068

0.019

0.344

0.244



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DATE 03 FEB 2016

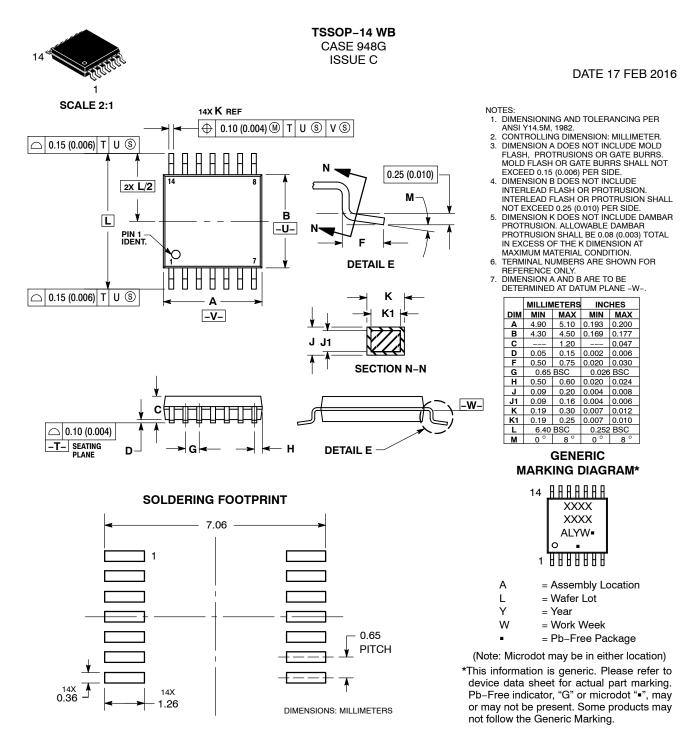
STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 2: CANCELLED	STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. ANODE/CATHODE 7. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON CATHODE 13. ANODE/CATHODE 14. ANODE/CATHODE	STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE

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